ESD701 Low Capacitance ESD Diode for RF and ADAS Signal Protection

1 Features

- IEC 61000-4-2 ESD Protection:
  - ±15kV contact discharge
  - ±15kV air gap discharge
- IEC 61000-4-5 surge protection:
  - 3A (8/20µs)
- I/O capacitance: 0.3pF (typical)
- Ultra low leakage current: 2nA (typical)
- Low dynamic resistance 0.84Ω (typical)
- Industry standard 0402 package

2 Applications

- Automotive Antenna ESD Protection
- RF Signal ESD Protection
- Near Field Communications (NFC)
- Automotive SerDes w/Power over Coax
- USB Type-C (short-to-Vbus tolerant)

3 Description

The ESD701 is a bidirectional ESD protection diode. The ESD701 is offered in the industry standard 0402 (DPY) package, and offers an IEC 61000-4-2 protection level of 15kV. The device can clamp 8/20µs surges with peak pulse currents up to 3A in accordance with the IEC 61000-4-5 standard.

The low capacitance and low leakage current help to ensure protection against transient events in a variety of systems and applications. This protection is key for many applications, such as smaller form factors and faster data speeds, which are becoming more popular over time.

Device Information

PART NUMBER	PACKAGE[1]	PACKAGE SIZE[2]
ESD701	DPY (X1SON, 2)	1mm × 0.6mm

(1) For more information, see Section 14.
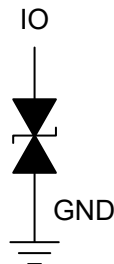(2) The package size (length × width) is a nominal value and includes pins, where applicable.

Figure 3-1. Functional Block Diagram

Table of Contents

4 Pin Configuration and Functions

Figure 4-1. DPY Package, 2-Pin X1SON (Top View)

Table 4-1. Pin Functions

PIN		TYPE[1]	DESCRIPTION
NAME	NO.		
IO	1	I/O	ESD Protected Channel. If used as ESD I/O, connect pin 2 to ground
IO	2	I/O	ESD Protected Channel. If used as ESD I/O, connect pin 1 to ground

(1)   I = input, O = output

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

Parameter		MIN	MAX	UNIT
P_{PPM}	IEC 61000-4-5 Surge (t_p = 8/20 µs) Peak Pulse Power at 25 °C [2]		210	W
I_{PPM}	IEC 61000-4-5 Surge (t_p = 8/20 µs) Peak Pulse Current at 25 °C [2]		3.0	A
T_A	Operating free-air temperature	−40	125	°C
T_{stg}	Storage temperature	−65	155	°C

(1)   Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2)   Voltages are with respect to GND unless otherwise noted.

5.2 ESD Ratings -JEDEC Specifications

Parameter		Test Conditions	VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	±2500	V
		Charged device model (CDM), per JEDEC specification JS-002, all pins[2]	±1000	

(1)   JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 ESD Ratings - IEC Specifications

Parameter		Test Conditions	VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	IEC 61000-4-2 Contact Discharge, all pins	±15000	V
		IEC 61000-4-2 Air Discharge, all pins	±15000	

5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage	-24		24	V
T_A	Operating Free Air Temperature	−40		125	°C

5.5 Thermal Information

THERMAL METRIC [1]		ESD701	UNIT
		DPY (X1SON)	
		2 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	262.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	132.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	2.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	78.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	NA	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.6 Electrical Characteristics

At TA = 25°C unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{RWM}	Reverse stand-off voltage	I_{IO} < 10 nA	-24		24	V
I_{LEAK}	Leakage current at V_{RWM}	VIO = ±24 V, I/O to GND		2	10	nA
V_{BR}	Breakdown voltage, I/O to GND [1]	I_{IO} = ±10 mA	25.5		35.5	V
V_{HOLD}	Holding voltage [2]	TLP, IO to GND or GND to IO		31		
V_{CLAMP}	Surge clamping voltage, t_p = 8/20 µs [3]	I_{PP} = 3 A, I/O to GND		37		V
V_{CLAMP}	Surge clamping voltage, t_p = 8/20 µs [3]	I_{PP} = 3 A, GND to I/O		37		V
V_{CLAMP}	TLP clamping voltage, t_p = 100 ns [4]	I_{PP} = 16 A (100 ns TLP), I/O to GND		41		V
V_{CLAMP}	TLP clamping voltage, t_p = 100 ns [4]	I_{PP} = 16 A (100 ns TLP), GND to I/O		41		V
R_{DYN}	Dynamic resistance [5]	I/O to GND		0.84		Ω
		GND to I/O		0.84		
C_{LINE}	Line capacitance, IO to GND	V_{IO} = 0 V, f = 1 MHz		0.3	0.5	pF

(1) V_{BR} is defined as the voltage obtained at 1 mA when sweeping the voltage up, before the device latches into the snapback state.
(2) V_{HOLD} is defined as the voltage when 1 mA is applied, after the device has successfully latched into the snapback state.
(3) Device stressed with 8/20 µs exponential decay waveform according to IEC 61000-4-5
(4) Non-repetitive square wave current pulse, Transmission Line Pulse (TLP); ANSI / ESD STM5.5.1-2008
(5) Extraction of R_{DYN} using least squares fit of TLP characteristics between I = 10 A and I = 20 A
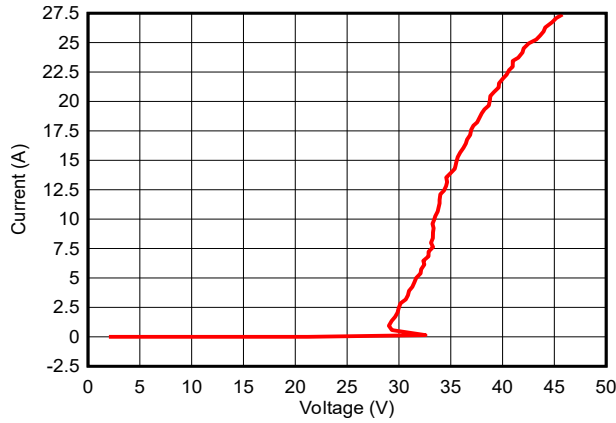
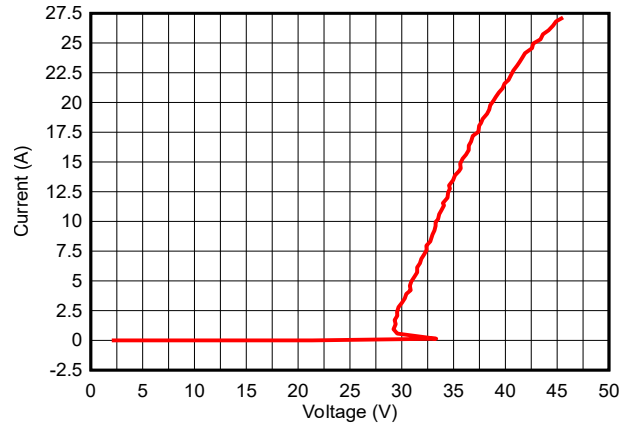## 5.7 Typical Characteristics

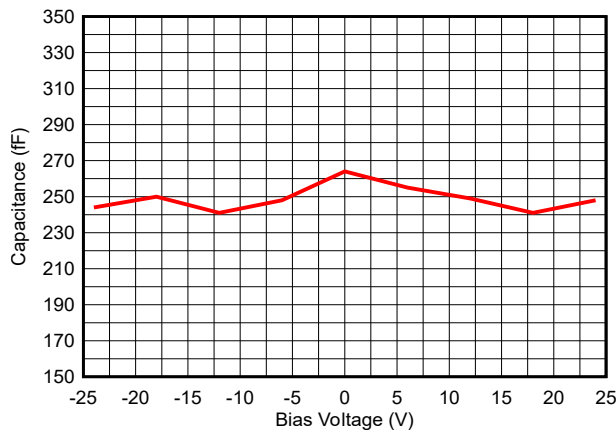**Figure 5-1. Positive TLP Curve**

Figure 5-2. Negative TLP Curve

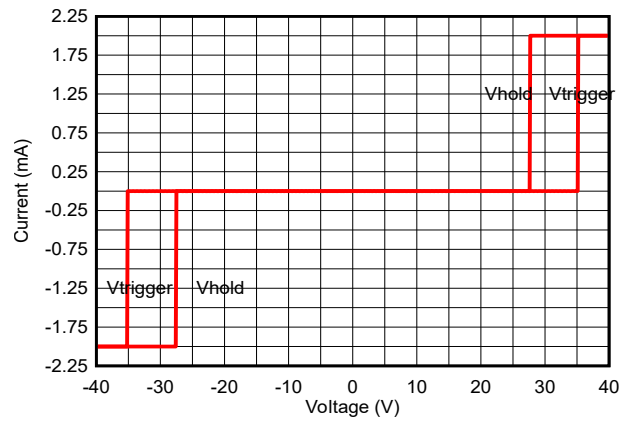**Figure 5-3. Bias Voltage vs. Capacitance**

Figure 5-4. DC-IV Curve
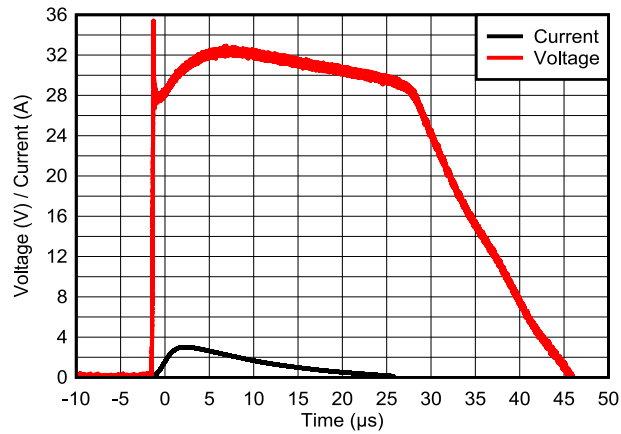
Figure 5-5. 8/20 µs Surge Response

6 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

6.1 Application Information

The ESD701 is a diode type TVS which is used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human interface connector and a system.

7 Device and Documentation Support

7.1 Documentation Support

7.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *ESD Packaging and Layout Guide*
- Texas Instruments, *TI's IEC 61000-4-x Testing application note*
- Texas Instruments, *ESD Layout Guide user's guide*
- Texas Instruments, *ESD Protection Diodes EVM user's guide*
- Texas Instruments, *Generic ESD Evaluation Module user's guide*
- Texas Instruments, *Reading and Understanding an ESD Protection Data Sheet user's guide*

7.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

7.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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7.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.6 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

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TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

13 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
October 2024	*	Initial Release

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ESD701DPYR	Active	Production	X1SON (DPY) | 2	10000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-55 to 150	PQ
ESD701DPYR.B	Active	Production	X1SON (DPY) | 2	10000 | LARGE T&R	-	Call TI	Call TI	-55 to 150	

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF ESD701 :

• Automotive : ESD701-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

Reel Diameter

Reel Width (W1)

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Sprocket Holes

User Direction of Feed

Pocket Quadrants

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ESD701DPYR	X1SON	DPY	2	10000	178.0	8.4	0.7	1.15	0.47	2.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

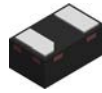| Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ESD701DPYR	X1SON	DPY	2	10000	205.0	200.0	33.0

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4231484/A

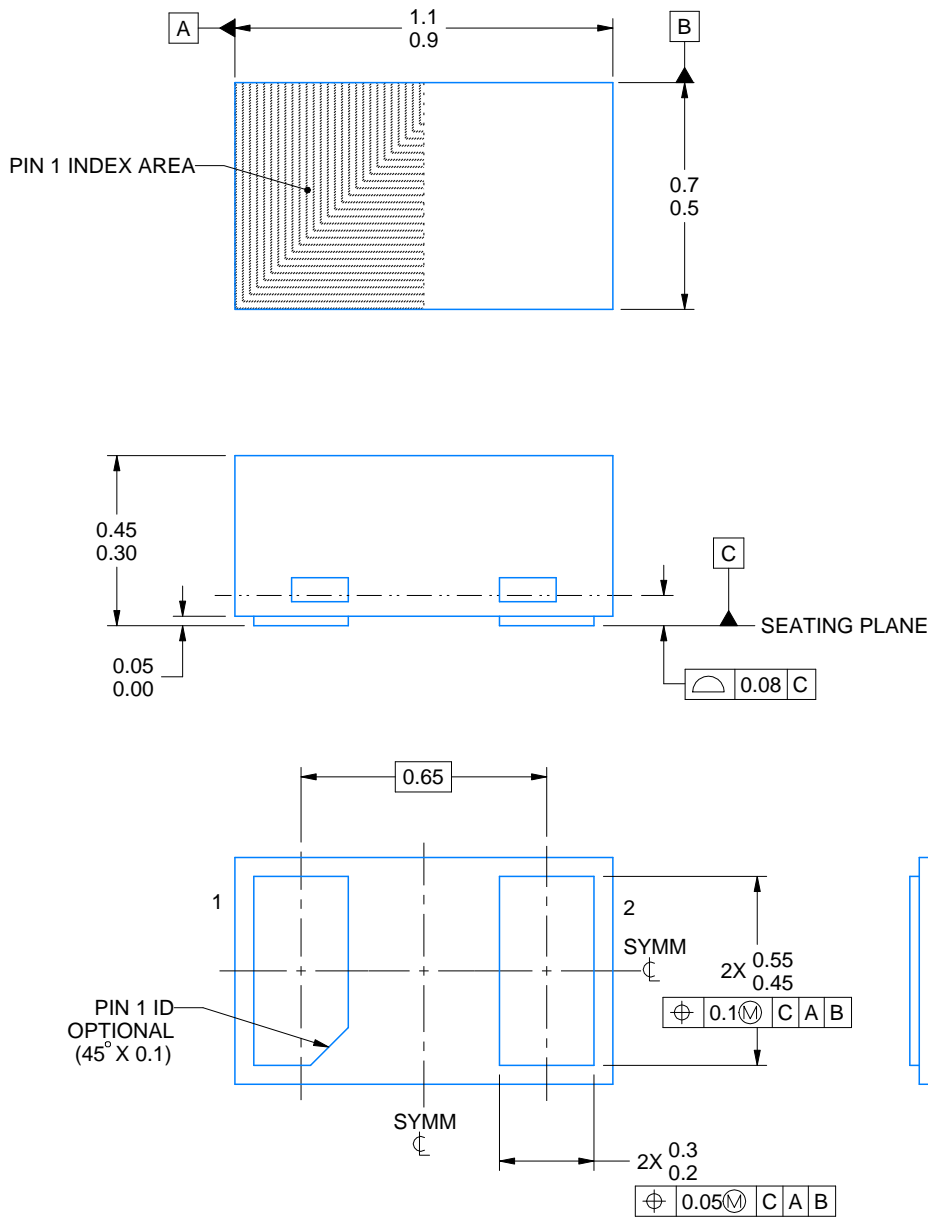PIN 1 INDEX AREA

1.1
0.9

0.7
0.5

0.45
0.30

0.05
0.00

C

SEATING PLANE

| △ | 0.08 | C |

0.65

1

2

SYMM
℄

2X 0.55
0.45

| ⊕ | 0.1 Ⓜ | C | A | B |

PIN 1 ID
OPTIONAL
(45° X 0.1)

SYMM
℄

2X 0.3
0.2

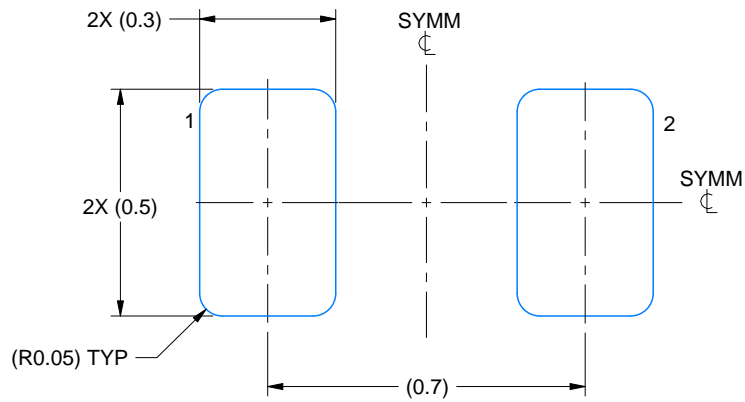| ⊕ | 0.05 Ⓜ | C | A | B |

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
2. This drawing is subject to change without notice.

2X (0.3)

SYMM
℄

1
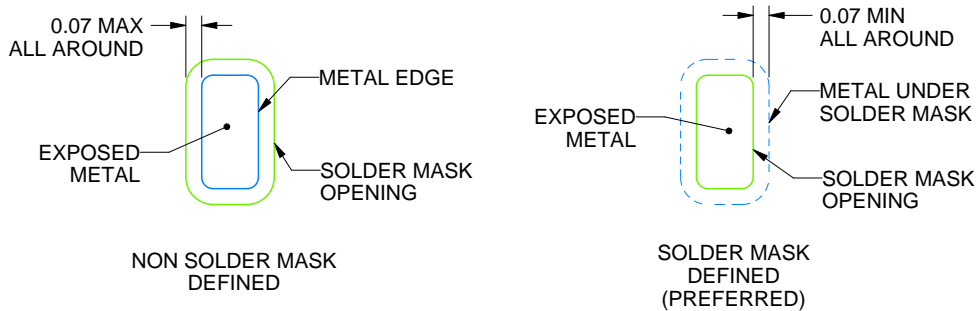
2

SYMM
℄

2X (0.5)

(R0.05) TYP

(0.7)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:60X

0.07 MAX
ALL AROUND

METAL EDGE

EXPOSED
METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED

0.07 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

EXPOSED
METAL

SOLDER MASK
OPENING

SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

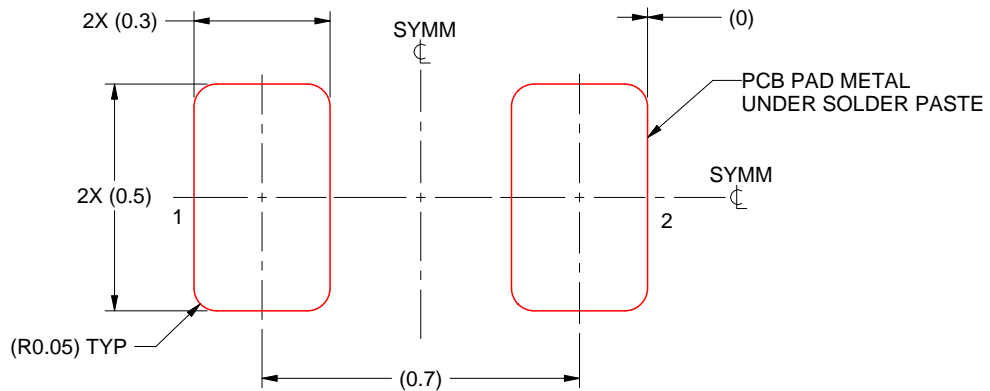4224561/C   07/2024

NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view.
   It is recommended that vias under paste be filled, plugged or tented.

2X (0.3)

SYMM
℄

(0)

PCB PAD METAL
UNDER SOLDER PASTE

2X (0.5)

SYMM
℄

1

2

(R0.05) TYP

(0.7)

SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:60X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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